

SANYO Semiconductors **DATA SHEET**

LA6517 LA6517M -LA6518M

Monolithic Linear IC

2-Output Power Operational Amplifier

Overview

The LA6517, LA6517M, and LA6518M are 2-output power operational amplifiers developed for use in consumer and industrial equipment.

Features

- High output current ($I_O \max = 0.5A$).
- High gain.
- Includes a current limiter.
- Wide operating voltage range (± 2 to $\pm 18V$).
- Single-supply operation possible (4 to 36V).
- Thermal shutdown built in.

Specifications

Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V _{CC} /V _{EE}		±18	V
Differential input voltage	V _{ID}		30	V
Common-mode input voltage	V _{IN}		±15	V
Allowable power dissipation	Pd max	LA6517	1000	mW
		LA6517M	350	mW
		LA6518M	700	mW
Operating temperature	Topr		-20 to +75	°C
Storage temperature	Tstg		-55 to +150	°C

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SANYO Semiconductor Co., Ltd.

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LA6517, 6517M, 6518M

Operating Conditions at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Recommended supply voltage	V _{CC} /V _{EE}		±2 to ±16	V

Electrical Characteristics at Ta = 25°C, $V_{CC}/V_{EE} = \pm 15V$

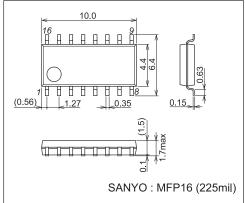
Parameter	Symbol	Conditions	min	typ	max	Unit
No-load current drain	Icc			8	20	mA
Input offset voltage	V _{IO}	$R_S \le 10k\Omega$		2	7	mV
Input offset current	ΙO			10	100	nA
Input bias current	IB			100	300	nA
Common-mode input voltage range	VICM	LA6517, 6517M	-15		+13	V
		LA6518M	-14		+13	V
Common-mode signal rejection ratio	CMRR		65	80		dB
Maximum output voltage	VO	$R_L = 33\Omega$	±11	±12		V
Voltage gain	VGO			85		dB
Slew rate	SR	$G_V = 0$, $R_L = 33\Omega$, $R = 10\Omega$, $L = 0.1\mu F$		0.15		V/μs
Supply voltage rejection ratio	SVR			30	300	μV/V
Limiting current (built in)	I _{SC}			0.5		Α

Package Dimensions

unit: mm (typ)

3001D [LA6517]

unit : mm (typ) 3035B [LA6517M]



unit : mm (typ) 3097B

3097B [LA6518M]

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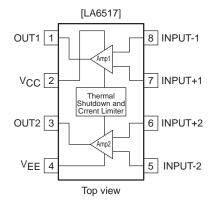
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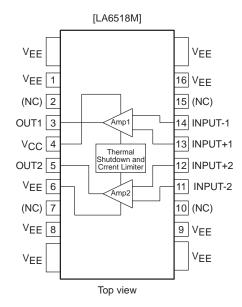
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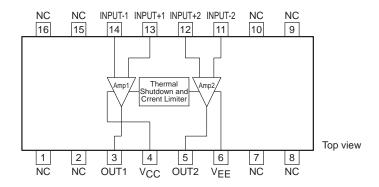
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Block Diagram and Pin Assignments

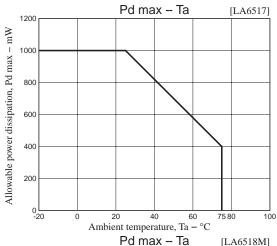


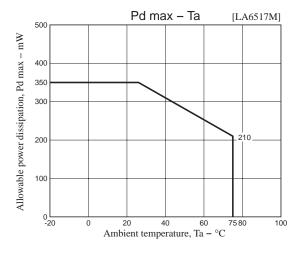


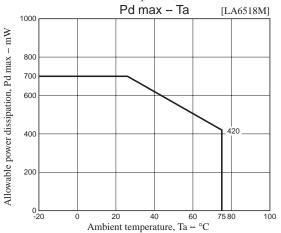
[LA6517M]



LA6517, 6517M, 6518M

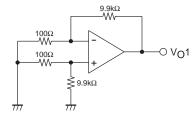


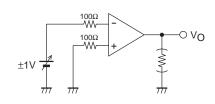




Test Circuits

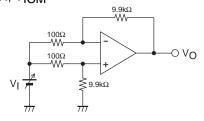
1. V_{IO}, SVRR





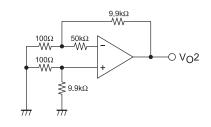
$$\begin{aligned} V_{IO} : V_{CC} / V_{EE} = & \pm 15V & V_{IO} = V_{O}1 / 100 \\ SVRR \begin{bmatrix} V_{CC} = 15V, 5V & SVR (+) \\ V_{EE} = -5V, -15V & SVR (-) \end{bmatrix} = \begin{vmatrix} \Delta V_{O}1 \\ 100 \times 10V \end{vmatrix} \end{aligned}$$

3. CMRR, VICM



$$\begin{split} &CMRR: V_I = \pm 7.5V \\ &CMR = 20log \left. \frac{15 \times 100}{\left| \Delta V_O \right|} \right. \end{split}$$

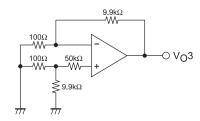
4. IB (-)



$$I_{B}(-) = \frac{|V_{O}2 - V_{O}1|}{50k\Omega \times 100}$$

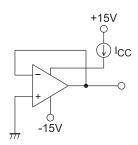
6. I₁O

5. IB (+)

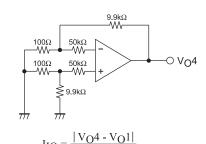


$$I_B(+) = \frac{|V_O 3 - V_O 1|}{50k\Omega \times 100}$$

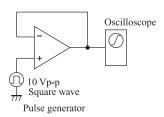
7. ICC

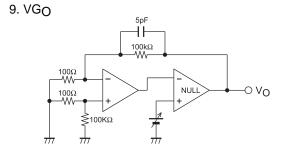


8. SR



 $50k\Omega \times 100$





$$VG_O = 20log \frac{1000 \times 20}{\Delta V_O}$$

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